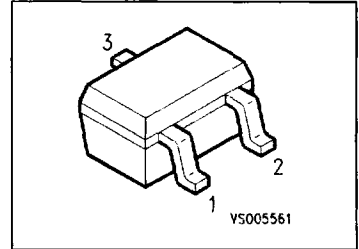


NPN Silicon AF Transistor

BC 846 W ... BC 850 W

Features

- For AF input stages and driver applications
- High current gain
- Low collector-emitter saturation voltage
- Low noise between 30Hz and 15 kHz
- Complementary types: BC 856 W, BC 857 W, BC 858 W, BC 859 W, BC 860 W (PNP)



Type	Marking	Ordering code (tape and reel)	Pin Configuration			Package
			1	2	3	
BC 846 AW	1 As	Q62702-C2319	B	E	C	SOT 323
BC 846 BW	1 Bs	Q62702-C2279				SOT 323
BC 847 AW	1 Es	Q62702-C2304				SOT 323
BC 847 BW	1 Fs	Q62702-C2305				SOT 323
BC 847 CW	1 Gs	Q62702-C2306				SOT 323
BC 848 AW	1 Js	Q62702-C2307				SOT 323
BC 848 BW	1 Ks	Q62702-C2308				SOT 323
BC 848 CW	1 Ls	Q62702-C2309				SOT 323
BC 849 BW	2 Bs	Q62702-C2310				SOT 323
BC 849 CW	2 Cs	Q62702-C2311				SOT 323
BC 850 BW	2 Fs	Q62702-C2312				SOT 323
BC 850 CW	2 Gs	Q62702-C2313				SOT 323

Maximum Ratings

Description	Symbol	BC846W BC 847 W BC 849 W BC 848 W BC 840 W			Unit
Collector-emitter voltage	V_{CE0}	65	45	30	V
Collector-base voltage	V_{CB0}	80	50	30	V
Collector-emitter voltage	V_{CES}	80	50	30	V
Emitter-base voltage	V_{EB0}	6	6	5	V
Collector current	I_C		100		mA
Collector peak current	I_{CM}		200		mA
Total power dissipation, $T_s = 115\text{ °C}$	P_{tot}		250		mW
Junction temperature	T_j		150		°C
Storage temperature range	T_{stg}		-65 to 150		°C

Thermal Resistance

Junction - ambient ¹⁾	$R_{th JA}$	≤ 240	K/W
Junction - soldering point	$R_{th JS}$	≤ 105	K/W

¹⁾Package mounted on epoxy pcb 40 mm × 40 mm × 1.5 mm/1 cm² Cu.

Characteristic at $T_A = 25^\circ\text{C}$, unless otherwise specified.

Description	Symbol	Ratings			Unit	
		min.	typ.	max.		
DC Characteristics						
Collector-emitter breakdown voltage $I_C = 10\text{ mA}$	$V_{(BR)CEO}$	BC 846 W	65	–	–	V
BC 847 W, BC 850 W		45	–	–		
BC 848 W, BC 849 W		30	–	–		
Collector-base breakdown voltage ¹⁾ $I_C = 100\ \mu\text{A}$	$V_{(BR)CBO}$	BC 846 W	80	–	–	V
BC 847 W, BC 850 W		50	–	–		
BC 848 W, BC 849 W		30	–	–		
Collector-emitter breakdown voltage $I_C = 10\ \mu\text{A}$, $V_{BE} = 0$	$V_{(BR)CBO}$	BC 846 W	80	–	–	V
BC 847 W, BC 850 W		50	–	–		
BC 848 W, BC 849 W		30	–	–		
Emitter-base breakdown voltage $I_E = 10\ \mu\text{A}$	$V_{(BR)EBO}$	BC 846 W, BC 847 W	6	–	–	V
BC 848 W, BC 849 W		5	–	–		
BC 850		–	–	–		
Collector-base cutoff current $V_{CB} = 30\text{ V}$ $V_{CB} = 30\text{ V}$, $T_A = 150^\circ\text{C}$	I_{CBO}		–	–	15	nA
			–	–	5	μA
DC current gain $I_C = 10\ \mu\text{A}$, $V_{CE} = 5\text{ V}$	h_{FE}	BC 846 AW ... BC 848 AW	–	140	–	–
		BC 846 BW ... BC 850 BW	–	250	–	
		BC 847 CW ... BC 850 CW	–	480	–	
$I_C = 2\text{ mA}$, $V_{CE} = 5\text{ V}$		BC 846 AW ... BC 848 AW	110	180	220	
		BC 846 BW ... BC 850 BW	200	290	450	
		BC 847 CW ... BC 850 CW	420	520	800	
Collector-emitter saturation voltage ¹⁾ $I_C = 10\text{ mA}$, $I_B = 0.5\text{ mA}$ $I_C = 100\text{ mA}$, $I_B = 5\text{ mA}$	V_{CEsat}		–	90	250	mV
			–	900	650	
Base-emitter saturation voltage ¹⁾ $I_C = 10\text{ mA}$, $I_B = 0.5\text{ mA}$ $I_C = 100\text{ mA}$, $I_B = 5\text{ mA}$	V_{CEsat}		–	700	–	mV
			–	900	–	
Base-emitter voltage ¹⁾ $I_C = 2\text{ mA}$, $V_{CE} = 0.5\text{ mA}$ $I_C = 10\text{ mA}$, $V_{CE} = 5\text{ mA}$	V_{CEsat}		580	660	700	mV
			–	–	770	

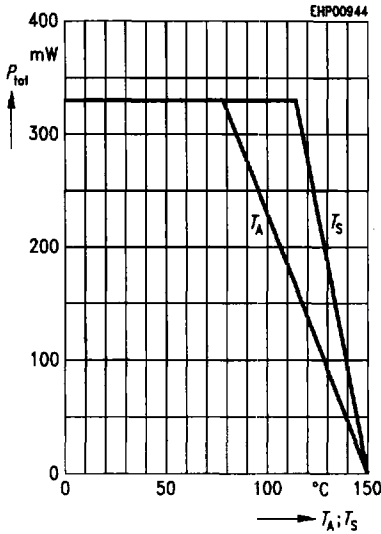
¹⁾Pulse test : $t \leq 300\ \mu\text{s}$, $D = 2\%$.

Characteristics at $T_A = 25^\circ\text{C}$, unless otherwise specified.

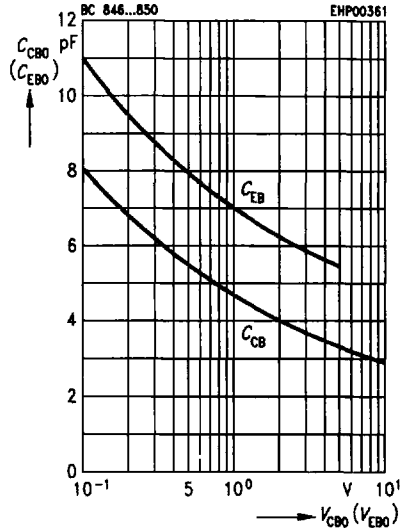
Description	Symbol	Ratings			Unit
		min.	typ.	max.	
AC Characteristics					
Transition frequency $I_C = 20\text{ mA}, V_{CE} = 5\text{ V}, f = 100\text{ MHz}$	f_T	–	250	–	MHz
Output capacitance $V_{CB} = 10\text{ V}, f = 1\text{ MHz}$	C_{ob0}	–	2	–	pF
Input capacitance $V_{EB} = 0.5\text{ V}, f = 1\text{ MHz}$	C_{ib0}	–	10	–	pF
Short-circuit input impedance $I_C = 2\text{ mA}, V_{CE} = 5\text{ V}, f = 1\text{ kHz}$ BC 846 AW ... BC 849 AW BC 846 BW ... BC 850 BW BC 847 CW ... BC 850 CW	h_{11e}	–	2.7 4.5 8.7	–	k Ω
Open-circuit reverse voltage transfer ratio $I_C = 2\text{ mA}, V_{CE} = 5\text{ V}, f = 1\text{ kHz}$ BC 846 AW ... BC 849 AW BC 846 BW ... BC 850 BW BC 847 CW ... BC 850 CW	h_{12e}	–	1.5 2.0 3.0	–	10^{-4}
Short-circuit forward current transfer ratio $I_C = 2\text{ mA}, V_{CE} = 5\text{ V}, f = 1\text{ kHz}$ BC 846 AW ... BC 849 AW BC 846 BW ... BC 850 BW BC 847 CW ... BC 850 CW	h_{21e}	–	200 330 600	–	
Open-circuit output admittance $I_C = 2\text{ mA}, V_{CE} = 5\text{ V}, f = 1\text{ kHz}$ BC 846 AW ... BC 849 AW BC 846 BW ... BC 850 BW BC 847 CW ... BC 850 CW	h_{22e}	–	18 30 60	–	μS
Noise figure $I_C = 0.2\text{ mA}, V_{CE} = 5\text{ V}, R_s = 2\text{ k}\Omega$ $f = 30\text{ Hz} \dots 15\text{ kHz}$ $f = 1\text{ kHz}, \Delta f = 200\text{ Hz}$ BC 849 W BC 850 W BC 849 W BC 850 W	F	–	1.4 1.4 1.2 1.0	4 3 4 4	dB
Equivalent noise voltage $I_C = 0.2\text{ mA}, V_{CE} = 5\text{ V}, R_s = 2\text{ k}\Omega$ $f = 10\text{ Hz} \dots 50\text{ Hz}$ BC 850 W	V_n	–	–	0.135	μV

Curves see BC 846 ... BC 840

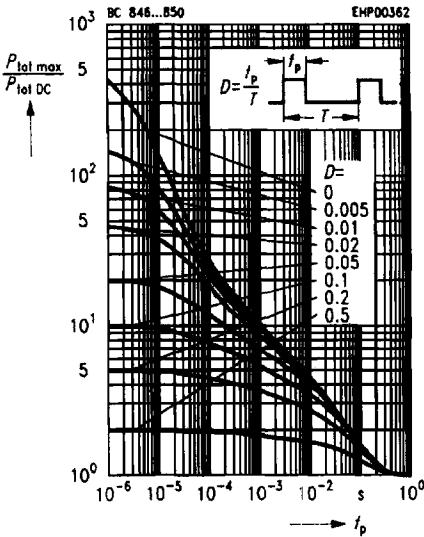
Total power dissipation $P_{tot} = f(T_A^*; T_S)$
 * Package mounted on epoxy



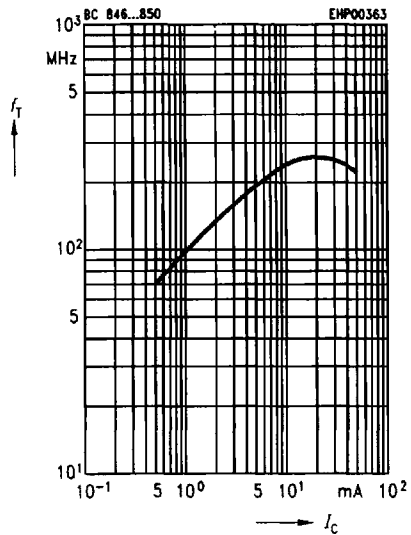
Collector-base capacitance $C_{CB0} = f(V_{CB0})$
Emitter-base capacitance $C_{EB0} = f(V_{EB0})$



Permissible pulse load $P_{tot max}/P_{tot DC} = f(t_p)$

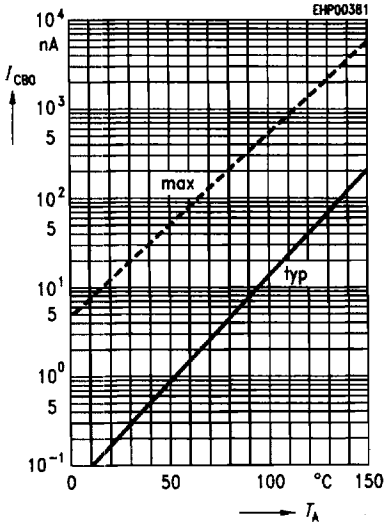


Transition frequency $f_T = f(I_C)$
 $V_{CE} = 5 V$



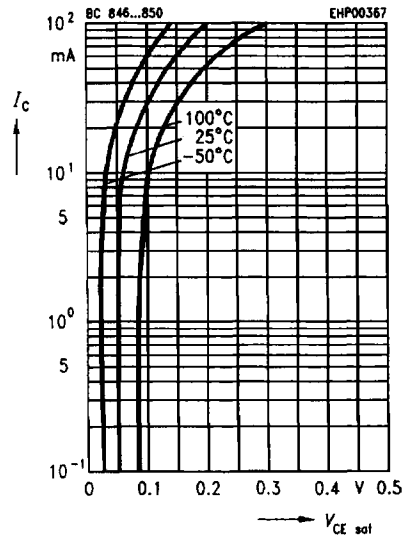
Collector cutoff current $I_{CB0} = f(T_A)$

$V_{CB} = 30 \text{ V}$



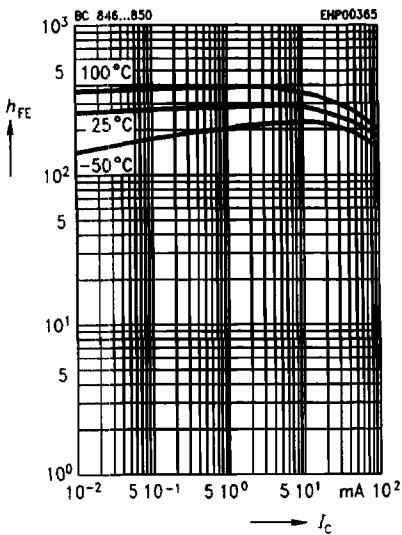
Collector-emitter saturation voltage

$I_C = f(V_{CEsat}), h_{FE} = 20$



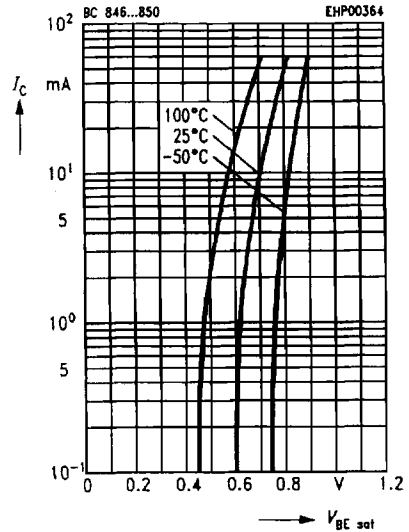
DC current gain $h_{FE} = f(I_C)$

$V_{CE} = 5 \text{ V}$

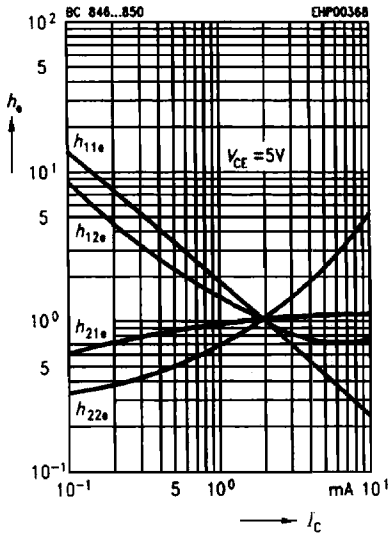


Base-emitter saturation voltage

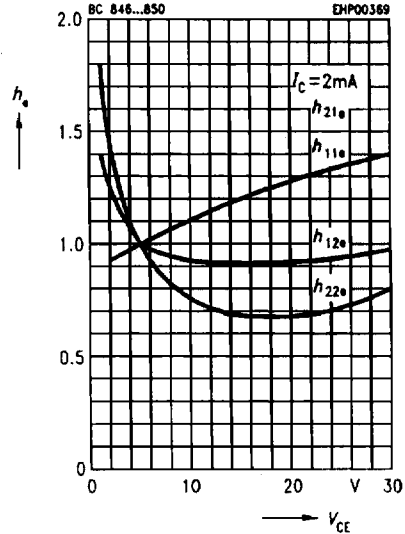
$I_C = f(V_{BEsat}), h_{FE} = 20$



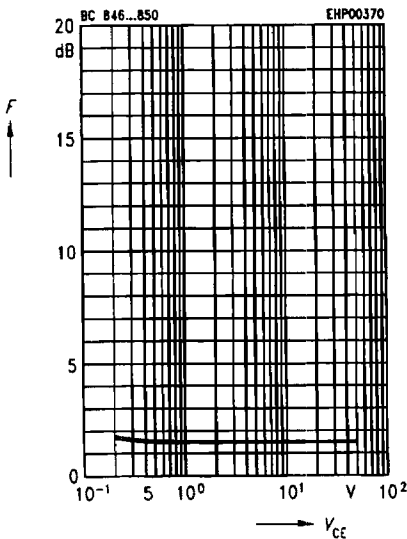
h parameter $h_o = f(I_C)$ normalized
 $V_{CE} = 5\text{ V}$



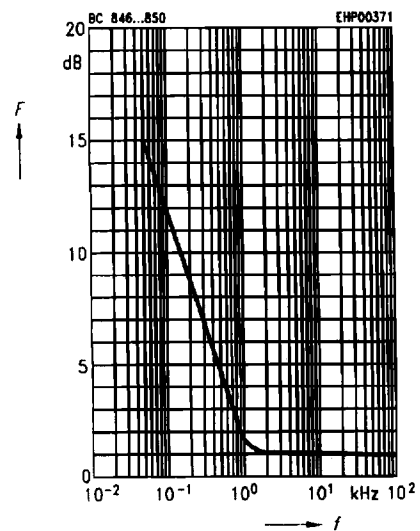
h parameter $h_o = f(V_{CE})$ normalized
 $I_C = 2\text{ mA}$



Noise figure $F = f(V_{CE})$
 $I_C = 0.2\text{ mA}$, $R_s = 2\text{ k}\Omega$, $f = 1\text{ kHz}$

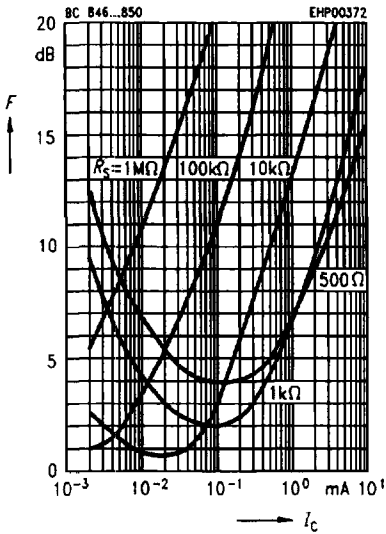


Noise figure $F = f(f)$
 $I_C = 0.2\text{ mA}$, $V_{CE} = 5\text{ V}$, $R_s = 2\text{ k}\Omega$



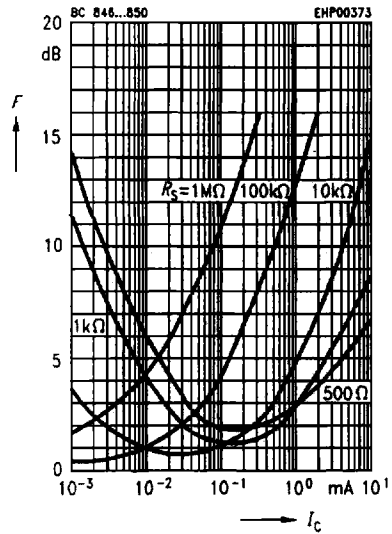
Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$, $f = 120 \text{ Hz}$



Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$, $f = 1 \text{ kHz}$



Noise figure $F = f(I_C)$

$V_{CE} = 5 \text{ V}$, $f = 10 \text{ kHz}$

